RoHS



www.vishay.com

### Vishay General Semiconductor

## **High Voltage Surface Mount Schottky Rectifier**

High Barrier Technology for Improved High Temperature Performance



DO-214AB (SMC)

PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	3.0 A				
$V_{RRM}$	90 V, 100 V				
I <sub>FSM</sub>	100 A				
V <sub>F</sub>	0.65 V				
I <sub>R</sub>	20 μΑ				
T <sub>J</sub> max.	175 °C				
Package	DO-214AB (SMC)				
Diode variations	Single				

#### **FEATURES**

- · Low profile package
- · Ideal for automated placement
- · Guardring for overvoltage protection
- Low power losses, high efficiency
- Low forward voltage drop
- Low leakage current
- High surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
  - Automotive ordering code: base P/NHE3
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### **TYPICAL APPLICATIONS**

For use in low voltage high frequency inverters, freewheeling, DC/DC converters, and polarity protection applications.

#### **MECHANICAL DATA**

Case: DO-214AB (SMC)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Base P/NHE3\_X - RoHS-compliant and AEC-Q101 qualified ("\_X" denotes revision code e.g. A, B, .....)

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 2 whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	SS3H9 SS3H10		UNIT	
Device marking code		MS9 MS10			
Maximum repetitive peak reverse voltage	$V_{RRM}$	90	100	V	
Working peak reverse voltage	V <sub>RWM</sub>	90	100	V	
Maximum DC blocking voltage	$V_{DC}$	90	100	V	
Maximum average forward rectified current at: T <sub>L</sub> = 115 °C	I <sub>F(AV)</sub>	3.0		А	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	100		А	
Peak repetitive reverse surge current at t <sub>p</sub> = 2.0 μs, 1 kHz	I <sub>RRM</sub>	1.0		А	
Critical rate of rise of reverse voltage	dV/dt	10 000		V/µs	
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-65 to	°C		



### Vishay General Semiconductor

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	SS3H9	SS3H10	UNIT
Maximum instantaneous forward voltage (1) $I_E = 3.0 \text{ A}$		T <sub>J</sub> = 25 °C		0.8		
Maximum instantaneous forward voltage (1)	I <sub>F</sub> = 3.0 A	T <sub>J</sub> = 125 °C	$V_{F}$	0.65		
Maximum reverse current at rated V <sub>R</sub> (2)		T <sub>J</sub> = 25 °C	1	20		μΑ
Iviaximum reverse current at rated $v_R \leftarrow$		T <sub>J</sub> = 125 °C	IR	4	1	mA

#### Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width  $\leq$  40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	SS3H9	SS3H10	UNIT	
Typical thermal resistance, junction to lead at T <sub>L</sub> = 25 °C	$R_{ heta JL}$	20		°C/W	
Typical thermal resistance, junction to ambient (1)	$R_{ heta JA}$	50		C/VV	

#### Note

(1) Units mounted on PCB with 0.55" x 0.55" (14 mm x 14 mm) copper pad areas

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
SS3H9-E3/57T	0.235	57T	850	7" diameter plastic tape and reel		
SS3H9-E3/9AT	0.235	9AT	3500	13" diameter plastic tape and reel		
SS3H9HE3_A/H (1)	0.235	Н	850	7" diameter plastic tape and reel		
SS3H9HE3_A/I (1)	0.235	1	3500	13" diameter plastic tape and reel		
SS3H9HE3_B/H (1)	0.235	Н	850	7" diameter plastic tape and reel		
SS3H9HE3_B/I (1)	0.235	I	3500	13" diameter plastic tape and reel		

#### Note

### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

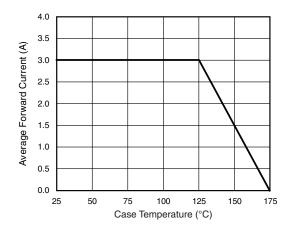


Fig. 1 - Forward Current Derating Curve

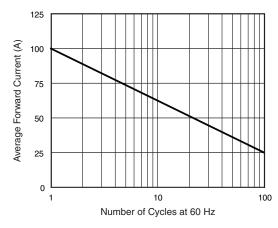


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

<sup>(1)</sup> AEC-Q101 qualified



### Vishay General Semiconductor

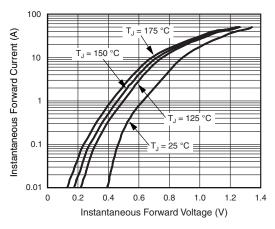


Fig. 3 - Typical Instantaneous Forward Characteristics

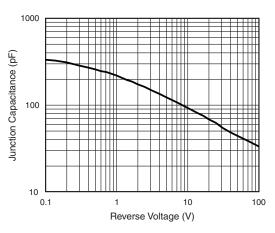


Fig. 5 - Typical Junction Capacitance

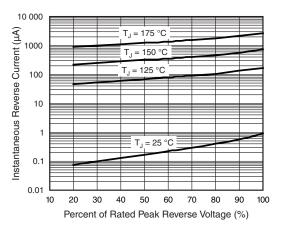


Fig. 4 - Typical Reverse Characteristics

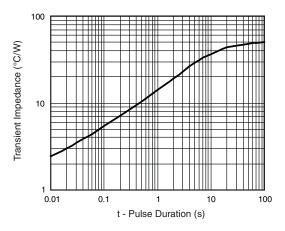
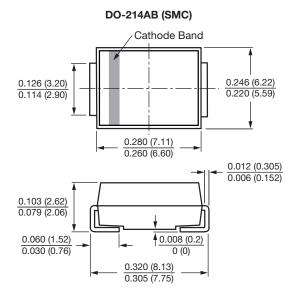
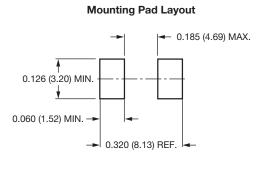


Fig. 6 - Typical Transient Thermal Impedance

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)







### **Legal Disclaimer Notice**

Vishay

### **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

# **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

### Vishay:

SS3H10/57T SS3H10/9AT SS3H10-E3/57T SS3H10-E3/59T SS3H10-E3/9AT SS3H10-E3/9CT SS3H10HE3/57T SS3H10HE3/59T SS3H10HE3/9AT SS3H10HE3/9CT SS3H9/59T SS3H9/9AT SS3H9/9CT SS3H9-E3/57T SS3H9-E3/57T SS3H9-E3/59T SS3H9-E3/9AT SS3H9-E3/9CT SS3H9HE3/59T SS3H9HE3/9AT SS3H9HE3/9CT SS3H9HE3/9AT SS3H9HE3/9CT SS3H9HE3/A/H SS3H10HE3\_A/H SS3H10HE3\_A/I SS3H9HE3\_B/I SS3H9HE3\_B/I SS3H9HE3\_B/I